8-bit serial-in/serial-out or parallel-out shift register with output latches

Rev. 5 — 4 July 2012

Product data sheet

1. General description

The 74AHC595; 74AHCT595 are high-speed Si-gate CMOS devices and are pin compatible with Low-power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard No. 7A.

The 74AHC595; 74AHCT595 are 8-stage serial shift registers with a storage register and 3-state outputs. The registers have separate clocks.

Data is shifted on the positive-going transitions of the shift register clock input (SHCP). The data in each register is transferred to the storage register on a positive-going transition of the storage register clock input (STCP). If both clocks are connected together, the shift register will always be one clock pulse ahead of the storage register.

The shift register has a serial input (DS) and a serial standard output (Q7S) for cascading. It is also provided with asynchronous reset (active LOW) for all 8 shift register stages. The storage register has 8 parallel 3-state bus driver outputs. Data in the storage register appears at the output whenever the output enable input (\overline{OE}) is LOW.

2. Features and benefits

- Balanced propagation delays
- All inputs have Schmitt-trigger action
- Inputs accept voltages higher than V_{CC}
- Input levels:
 - The 74AHC595 operates with CMOS input levels
 - The 74AHCT595 operates with TTL input levels
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C

3. Applications

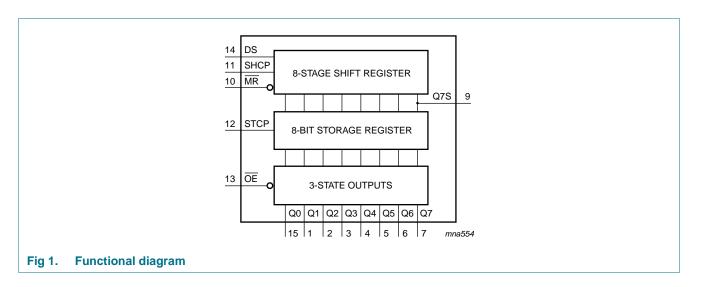
- Serial-to-parallel data conversion
- Remote control holding register



4. Ordering information

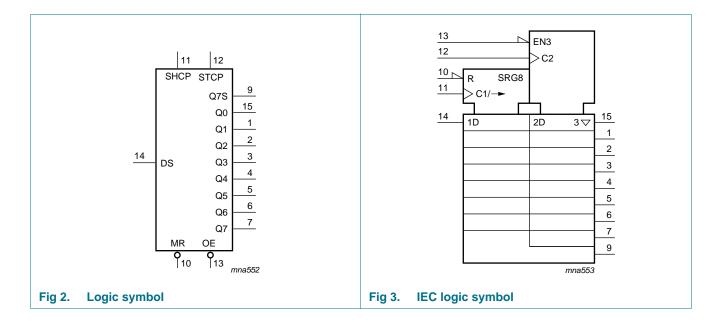
Table 1. Orderin	g information			
Type number	Package			
	Temperature range	Name	Description	Version
74AHC595				
74AHC595D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHC595PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74AHC595BQ	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	SOT763-1
74AHCT595				
74AHCT595D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHCT595PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74AHCT595BQ	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	SOT763-1

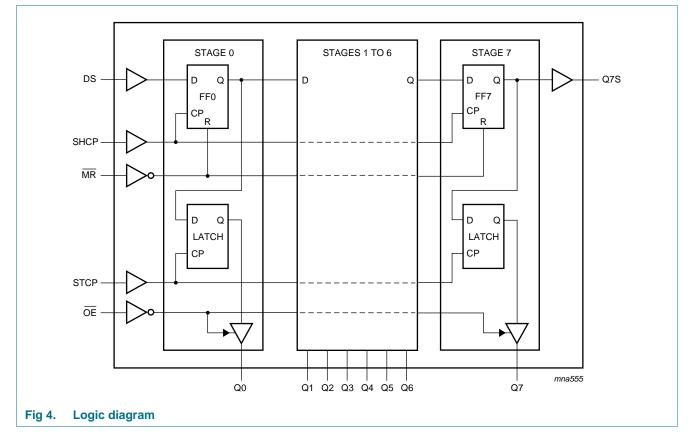
5. Functional diagram



74AHC595; 74AHCT595

8-bit serial-in/serial-out or parallel-out shift register with output latches





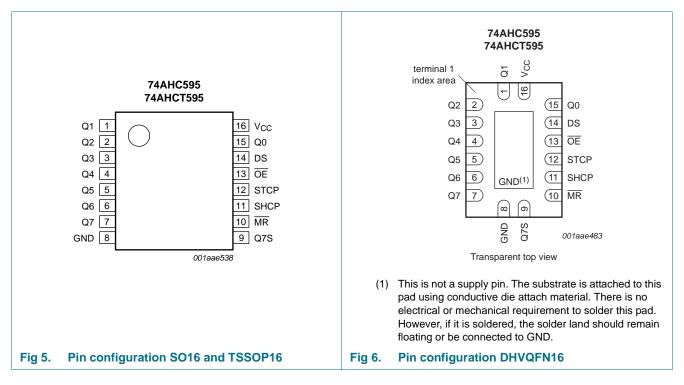
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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
Q1	1	parallel data output 1
Q2	2	parallel data output 2
Q3	3	parallel data output 3
Q4	4	parallel data output 4
Q5	5	parallel data output 5
Q6	6	parallel data output 6
Q7	7	parallel data output 7
GND	8	ground (0 V)
Q7S	9	serial data output
MR	10	master reset (active LOW)
SHCP	11	shift register clock input
STCP	12	storage register clock input
OE	13	output enable input (active LOW)
DS	14	serial data input
Q0	15	parallel data output 0
V _{CC}	16	supply voltage

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7. Functional description

Contro	bl			Input	Outpu	ıt	Function
SHCP	STCP	OE	MR	DS	Q7S	Qn	
Х	Х	L	L	Х	L	NC	a LOW-level on $\overline{\text{MR}}$ only affects the shift registers
Х	\uparrow	L	L	Х	L	L	empty shift register loaded into storage register
Х	Х	Н	L	Х	L	Z	shift register clear; parallel outputs in high-impedance OFF-state
↑	Х	L	Н	Η	Q6S	NC	logic HIGH-level shifted into shift register stage 0. Contents of all shift register stages shifted through, e.g. previous state of stage 6 (internal Q6S) appears on the serial output (Q7S).
X	↑	L	Н	Х	NC	QnS	contents of shift register stages (internal QnS) are transferred to the storage register and parallel output stages
↑	↑	L	Н	х	Q6S	QnS	contents of shift register shifted through; previous contents of the shift register is transferred to the storage register and the parallel output stages

[1] H = HIGH voltage state;

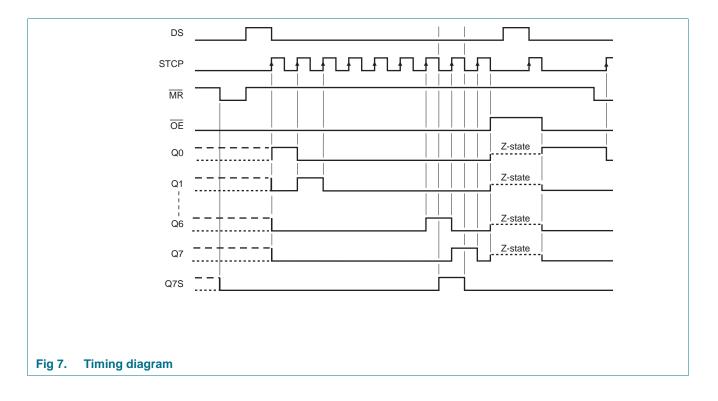
L = LOW voltage state;

 \uparrow = LOW-to-HIGH transition;

X = don't care;

NC = no change;

Z = high-impedance OFF-state.



8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	<u>[1]</u> –20	-	mA
I _{OK}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> –20	+20	mA
lo	output current	$V_{\rm O}$ = –0.5 V to (V_{\rm CC} + 0.5 V)	-25	+25	mA
I _{CC}	supply current		-	+75	mA
I _{GND}	ground current		-75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C	[2] _	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SO16 packages: above 70 °C the value of P_{tot} derates linearly at 8 mW/K.
 For TSSOP16 packages: above 60 °C the value of P_{tot} derates linearly at 5.5 mW/K.
 For DHVQFN16 packages: above 60 °C the value of P_{tot} derates linearly at 4.5 mW/K.

9. Recommended operating conditions

Table 5.	Operating conditions					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74AHC59	95					
V _{CC}	supply voltage		2.0	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 3.0 V to 3.6 V	-	-	100	ns/V
		V_{CC} = 4.5 V to 5.5 V	-	-	20	ns/V
74AHCT5	595					
V _{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 4.5 V to 5.5 V	-	-	20	ns/V

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C	;	-40 °C	to +85 °C	–40 °C to +125 °C		Uni
			Min	Тур	Max	Min	Max	Min	Max	
74AHC5	95			1		1				1
VIH	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{он}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = -50 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -50 \ \mu A; \ V_{CC} = 3.0 \ V$	2.9	3.0	-	2.9	-	2.9	-	V
		$I_{O} = -50 \ \mu A; V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_0 = 50 \ \mu A; V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{\rm O} = 50 \ \mu \text{A}; \ V_{\rm CC} = 3.0 \ \text{V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 50 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
		I _O = 8.0 mA; V _{CC} = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL};$ $V_{O} = V_{CC} \text{ or } \text{GND}; V_{CC} = 5.5 \text{ V}$	-	-	±0.25	-	±2.5	-	±10	μA
I _{CC}		$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	4.0	-	40	-	80	μA
Cı	input capacitance		-	3	10	-	10	-	10	pF
74АНСТ	595									
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V _{он}	HIGH-level	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$								
	output voltage	$I_{\rm O} = -50 \ \mu {\rm A}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{\rm O} = -8.0 \rm{mA}$	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$								
	output voltage	$I_{O} = 50 \ \mu A$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 8.0 \text{ mA}$	-	-	0.36	-	0.44	-	0.55	V

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Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C	;	–40 °C t	o +85 °C	–40 °C t	o +125 °C	Unit
				Тур	Max	Min	Max	Min	Max	-
I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I _{OZ}	OFF-state output current		-	-	±0.25	-	±2.5	-	±10	μΑ
I _{CC}	supply current		-	-	4.0	-	40	-	80	μA
ΔI_{CC}	additional supply current	per input pin; V _I = V _{CC} $- 2.1$ V; other inputs at V _{CC} or GND; I _O = 0 A; V _{CC} = 4.5 V to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
CI	input capacitance		-	3	10	-	10	-	10	pF

8-bit serial-in/serial-out or parallel-out shift register with output latches

11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 13</u>.

Symbol	Parameter	Conditions			25 °C		−40 °C	to +85 °C	–40 °C t	to +125 °C	Unit
				Min	Typ[1]	Мах	Min	Max	Min	Max	
74AHC5	95										
t _{pd}	propagation	SHCP to Q7S; see Figure 8	[2]								
	delay	V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.7	13.0	1.0	15.0	1.0	16.5	ns
		C _L = 50 pF		-	7.7	16.5	1.0	18.5	1.0	20.1	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.0	8.2	1.0	9.4	1.0	10.5	ns
		C _L = 50 pF		-	5.4	10.0	1.0	11.4	1.0	12.5	ns
		STCP to Qn; see Figure 9	[2]								
		V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.9	11.9	1.0	13.5	1.0	15.0	ns
		C _L = 50 pF		-	7.7	15.4	1.0	17.0	1.0	18.5	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.2	7.4	1.0	8.5	1.0	9.5	ns
		C _L = 50 pF		-	5.5	9.0	1.0	10.5	1.0	11.5	ns
		MR to Q7S; see Figure 11	[3]								
		V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.9	12.8	1.0	13.7	1.0	15.0	ns
		C _L = 50 pF		-	7.4	16.3	1.0	17.2	1.0	18.7	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.4	8.0	1.0	9.1	1.0	10.0	ns
		C _L = 50 pF		-	5.6	10.0	1.0	11.1	1.0	12.0	ns
en	enable time	OE to Qn; see Figure 12	[4]								
		V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.6	11.5	1.0	13.5	1.0	15.0	ns
		C _L = 50 pF		-	7.4	15.0	1.0	17.0	1.0	18.5	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.0	8.6	1.0	10.0	1.0	11.0	ns
		C _L = 50 pF		-	5.3	10.6	1.0	12.0	1.0	13.0	ns
dis	disable time	OE to Qn; see Figure 12	[5]								
		V _{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.4	11.0	1.0	13.0	1.0	14.5	ns
		$C_L = 50 \text{ pF}$		-	8.7	15.7	1.0	16.2	1.0	17.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		$C_L = 15 \text{pF}$		-	3.8	8.0	1.0	9.5	1.0	10.5	ns
		$C_L = 50 \text{ pF}$		-	5.8	10.3	1.0	11.0	1.0	12.0	ns

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Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 13.

Symbol	Parameter	Conditions			25 °C		–40 °C	to +85 °C	–40 °C t	to +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
max	maximum frequency	SHCP or STCP; see <u>Figure 8</u> and <u>9</u>									
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		80	125	-	60	-	40	-	MH
		V_{CC} = 4.5 V to 5.5 V		130	170	-	110	-	90	-	MH
W	pulse width	SHCP HIGH or LOW; see <u>Figure 8</u>									
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		V_{CC} = 4.5 V to 5.5 V		5.0	-	-	5.0	-	5.0	-	ns
		STCP HIGH or LOW; see <u>Figure 9</u>									
		V_{CC} = 3.0 V to 3.6 V		5.0	-	-	5.0	-	5.0	-	ns
		V_{CC} = 4.5 V to 5.5 V		5.0	-	-	5.0	-	5.0	-	ns
		MR LOW; see Figure 11									
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		$V_{CC} = 4.5 V \text{ to } 5.5 V$		5.0	-	-	5.0	-	5.0	-	ns
su	set-up time	DS to SHCP; see Figure 9									
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		3.5	-	-	3.5	-	3.5	-	ns
		V_{CC} = 4.5 V to 5.5 V		3.0	-	-	3.0	-	3.0	-	ns
		SHCP to STCP; see <u>Figure 10</u>									
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		8.5	-	-	8.5	-	8.5	-	ns
		V_{CC} = 4.5 V to 5.5 V		5.0	-	-	5.0	-	5.0	-	ns
h	hold time	DS to SHCP; see Figure 10									
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.5	-	-	1.5	-	1.5	-	ns
		V_{CC} = 4.5 V to 5.5 V		2.0	-	-	2.0	-	2.0	-	ns
rec	recovery	MR to SHCP; see Figure 11									
	time	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		3.0	-	-	3.0	-	3.0	-	ns
		V_{CC} = 4.5 V to 5.5 V		2.5	-	-	2.5	-	2.5	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{\text{CC}}$	<u>[6]</u> [7]	-	180	-	-	-	-	-	pF
74AHCT	595; V _{CC} = 4.	5 V to 5.5 V									
pd	propagation	SHCP to Q7S; see Figure 8	[2]								
	delay	C _L = 15 pF		-	3.8	8.2	1.0	9.0	1.0	10.0	ns
		C _L = 50 pF		-	5.2	10.0	1.0	11.0	1.0	12.0	ns
		STCP to Qn; see Figure 9	[2]								
		C _L = 15 pF		-	4.0	7.4	1.0	8.5	1.0	9.5	ns
		$C_{L} = 50 \text{pF}$		-	5.3	9.0	1.0	10.5	1.0	11.5	ns
		MR to Q7S; see Figure 11	[3]								
		C _L = 15 pF		-	4.6	8.2	1.0	9.5	1.0	10.5	ns
		$C_L = 50 \text{ pF}$		-	5.8	10.5	1.0	11.5	1.0	12.5	ns
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Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 13.

Symbol	Parameter	Conditions			25 °C		–40 °C	to +85 °C	–40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
t _{en}	enable time	OE to Qn; see Figure 12	[4]					'			
		C _L = 15 pF		-	4.8	9.0	1.0	11.0	1.0	12.0	ns
		C _L = 50 pF		-	6.2	11.6	1.0	13.0	1.0	14.5	ns
t _{dis}	disable time	OE to Qn; see Figure 12	[5]								
		C _L = 15 pF		-	3.6	6.9	1.0	8.0	1.0	9.0	ns
		C _L = 50 pF		-	5.8	10.3	1.0	11.0	1.0	12.0	ns
f _{max}	maximum frequency	SHCP and STCP; see <u>Figure 8</u> and <u>9</u>		130	170	-	110	-	90	-	MHz
t _W	pulse width	SHCP HIGH or LOW; see <u>Figure 8</u>		5.0	-	-	5.0	-	5.0	-	ns
		STCP HIGH or LOW; see Figure 9		5.0	-	-	5.0	-	5.0	-	ns
		MR LOW; see Figure 11		5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	DS to SHCP; see Figure 9		3.0	-	-	3.0	-	3.0	-	ns
		SHCP to STCP; see Figure 10		5.0	-	-	5.0	-	5.0	-	ns
t _h	hold time	DS to SHCP; see Figure 10		2.0	-	-	2.0	-	2.0	-	ns
t _{rec}	recovery time	MR to SHCP; see Figure 11		3.0	-	-	3.0	-	3.0	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_i = \text{GND to } V_{\text{CC}}$	<u>[6]</u> [7]	-	190	-	-	-	-	-	рF

[1] Typical values are measured at nominal supply voltage.

 $\label{eq:tpd} [2] \quad t_{pd} \text{ is the same as } t_{PHL} \text{ and } t_{PLH}.$

[3] t_{pd} is the same as t_{PHL} only.

[4] t_{en} is the same as t_{PZL} and t_{PZH} .

[5] t_{dis} is the same as t_{PLZ} and t_{PHZ} .

[6] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o) = \text{sum of outputs};$

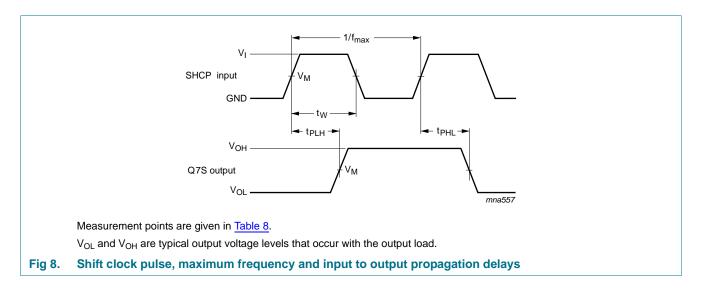
 C_L = output load capacitance in pF;

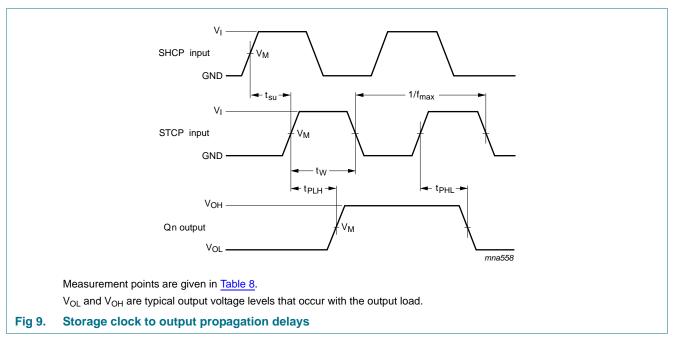
 V_{CC} = supply voltage in V.

[7] All 9 outputs switching.

8-bit serial-in/serial-out or parallel-out shift register with output latches

12. Waveforms





74AHC595; 74AHCT595

8-bit serial-in/serial-out or parallel-out shift register with output latches

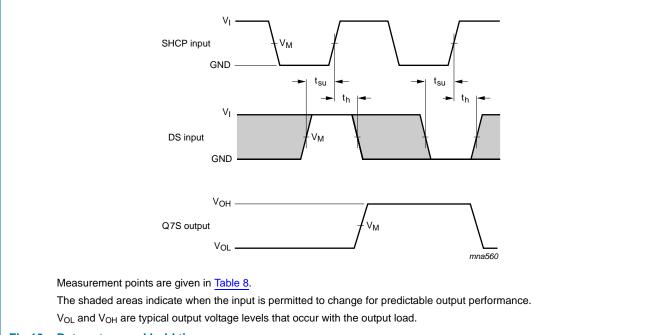
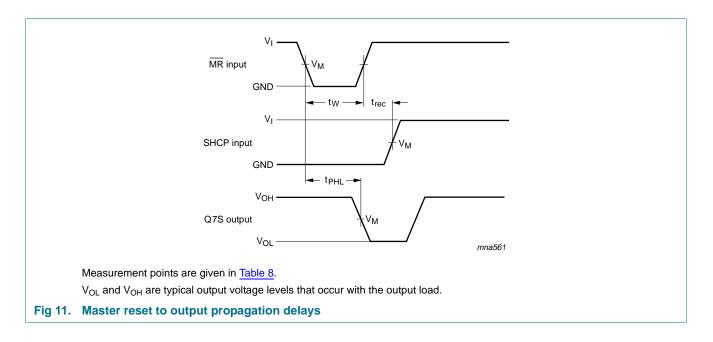


Fig 10. Data set-up and hold times



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8-bit serial-in/serial-out or parallel-out shift register with output latches

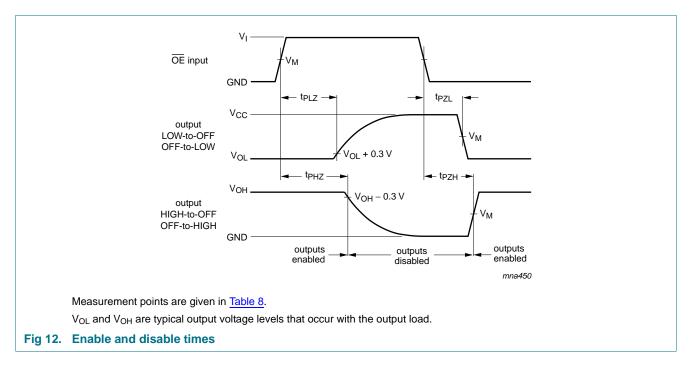


Table 8.Measurement points

Туре	Input	Output
	V _M	V _M
74AHC595	0.5V _{CC}	0.5V _{CC}
74AHCT595	1.5 V	0.5V _{CC}

74AHC595; 74AHCT595

8-bit serial-in/serial-out or parallel-out shift register with output latches

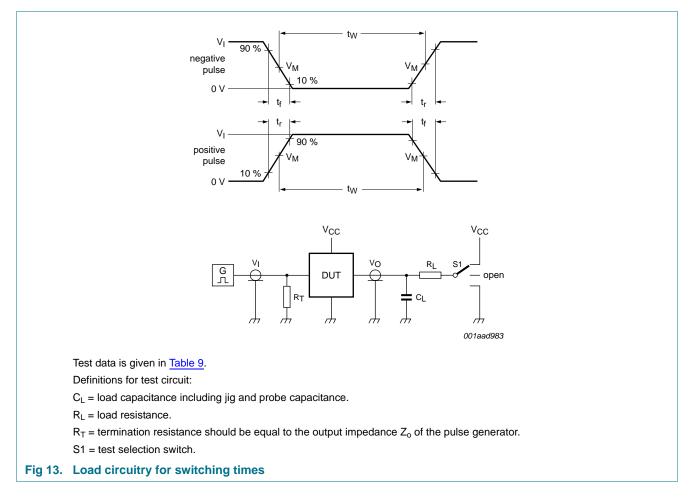


Table 9. Test data

Туре	Input		Load		S1 position			
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
74AHC595	V _{CC}	\leq 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	
74AHCT595	3.0 V	\leq 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	

74AHC595; 74AHCT595

8-bit serial-in/serial-out or parallel-out shift register with output latches

13. Package outline

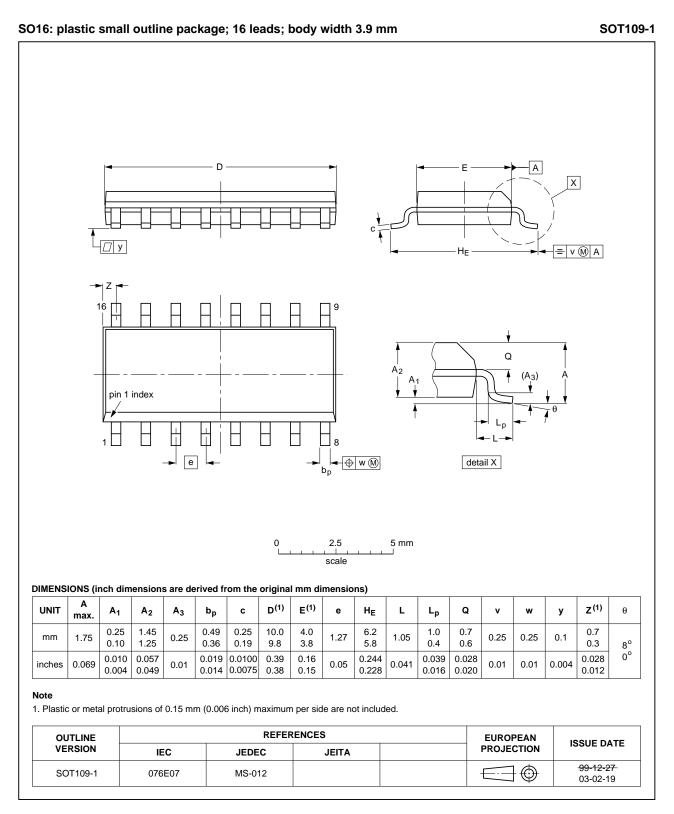


Fig 14. Package outline SOT109-1 (SO16)

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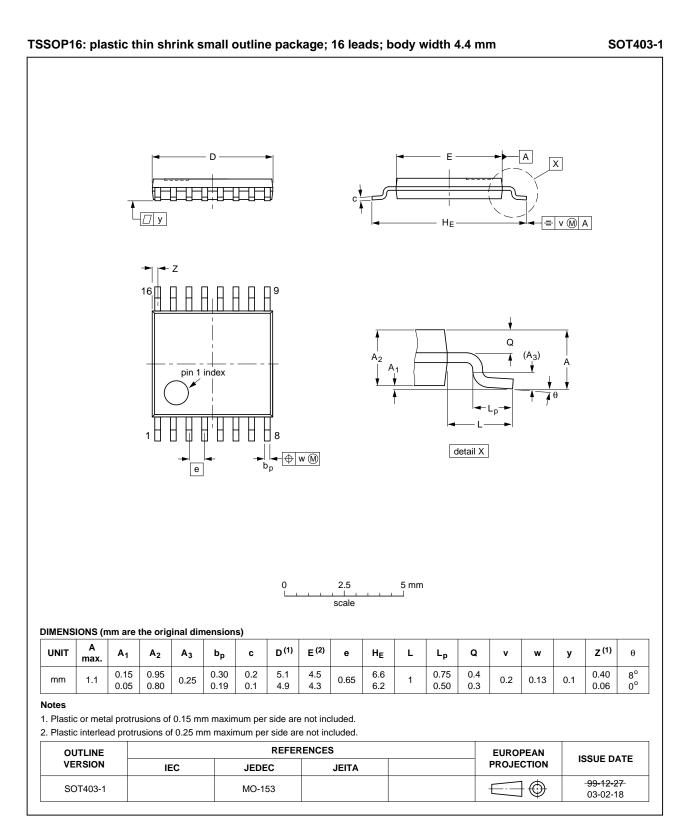
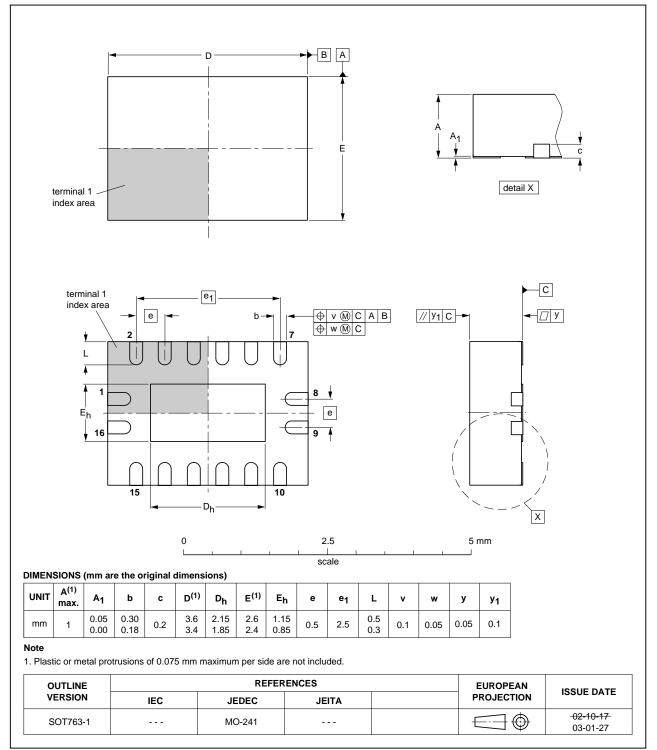


Fig 15. Package outline SOT403-1 (TSSOP16)

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

Fig 16. Package outline SOT763-1 (DHVQFN16)

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14. Abbreviations

Table 10. Abbreviations				
Acronym	Description			
CDM	Charged Device Model			
CMOS	Complementary Metal-Oxide Semiconductor			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			
TTL	Transistor-Transistor Logic			

15. Revision history

Table 11. Revision history							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AHC_AHCT595 v.5	20120704	Product data sheet	-	74AHC_AHCT595 v.4			
Modifications: Added GND in the pin configuration drawing DHVQFN16 (errata) 							
74AHC_AHCT595 v.4	20090811	Product data sheet	-	74AHC_AHCT595 v.3			
74AHC_AHCT595 v.3	20080425	Product data sheet	-	74AHC_AHCT595 v.2			
74AHC_AHCT595 v.2	20060323	Product data sheet	-	74AHC_AHCT595 v.1			
74AHC_AHCT595 v.1	20000315	Product specification	-	-			

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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74AHC_AHCT595
Product data sheet

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